



YJG220G06AR

RECOMMEND
YJG210G06AR
FOR NEW DESIGN

N-Channel Enhancement Mode Field Effect Transistor

Product Summary

V_{DS}

60V



YJG220G06AR

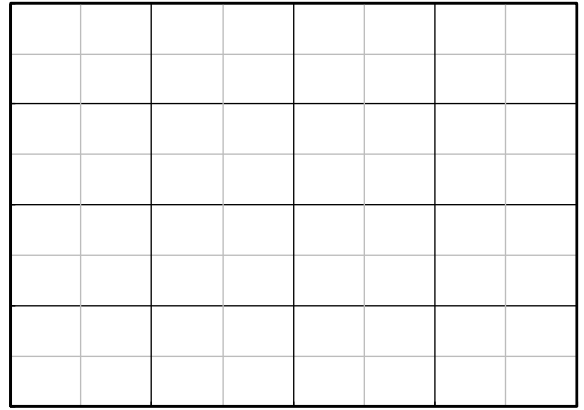
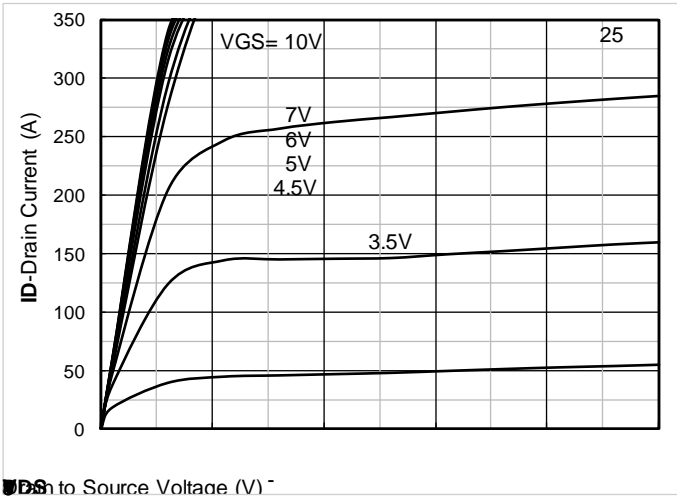
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Electrical Characteristics ($T_J=25$ unless otherwise noted)

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
|--------------------------------|------------|---------------------------|-----|-----|-----|-------|
| Static Parameter | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=250\mu A$ | 60 | - | - | V |



Typical Electrical and Thermal Characteristics Diagrams



Figure

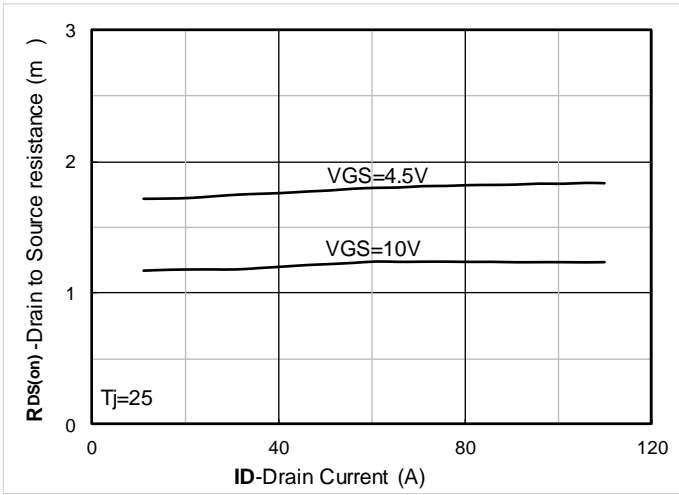


Figure 7. RDS(on) vs Drain Current

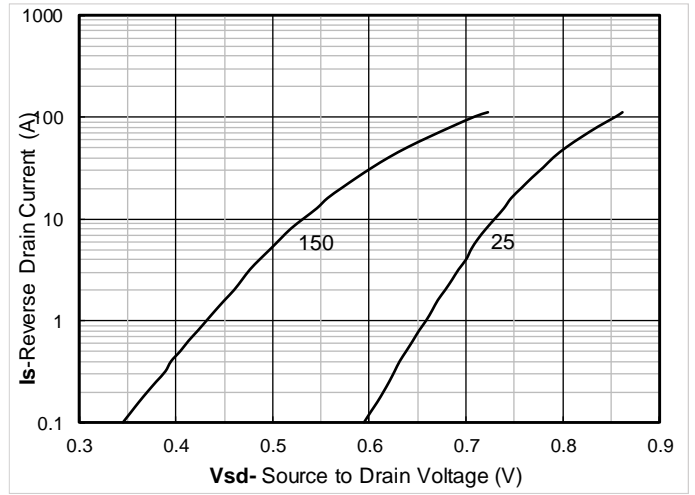


Figure 8. Forward characteristics of reverse diode



Figure 9. Normalized breakdown voltage



Figure 10. Normalized Threshold voltage

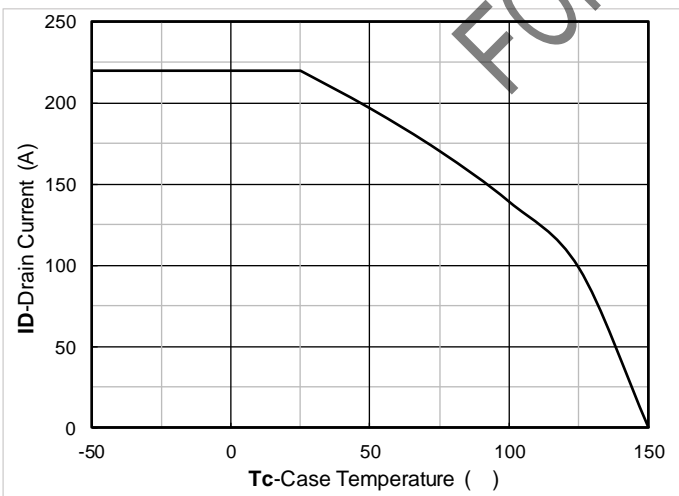


Figure 11. Current dissipation

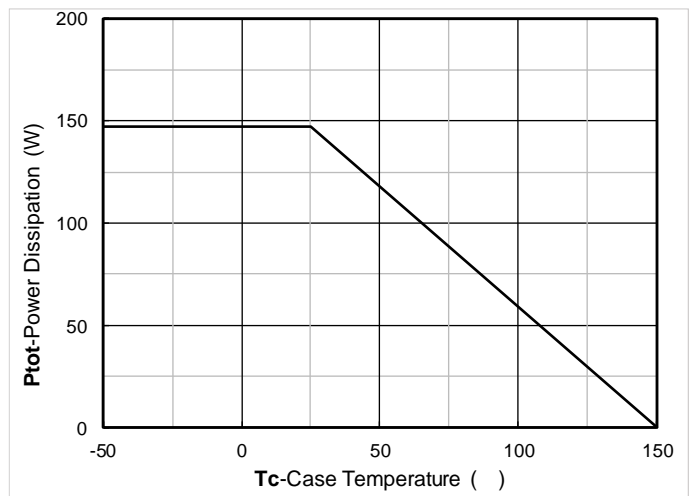


Figure 12. Power dissipation

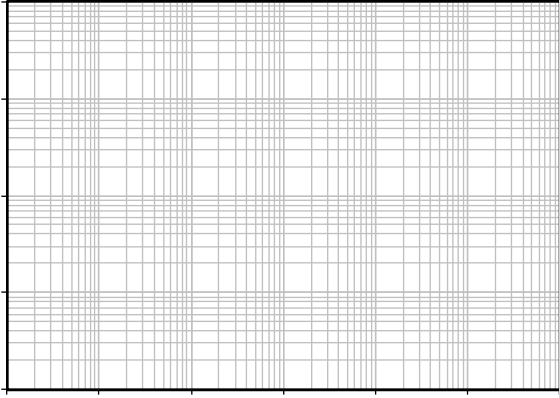


Figure 13. Maximum Transient Thermal Impedance

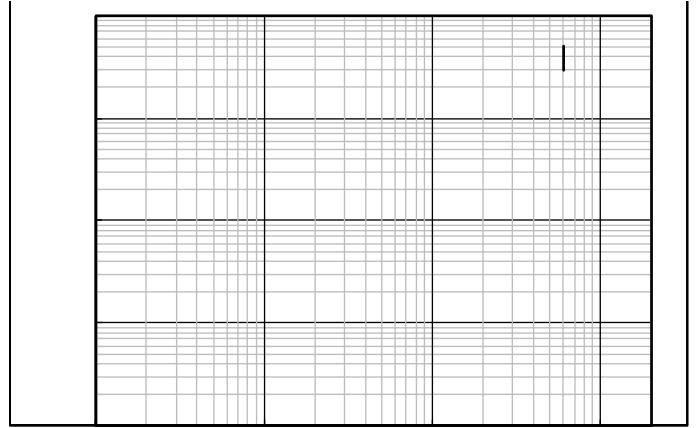


Figure 14. Safe Operation Area

Test Circuits & Waveforms

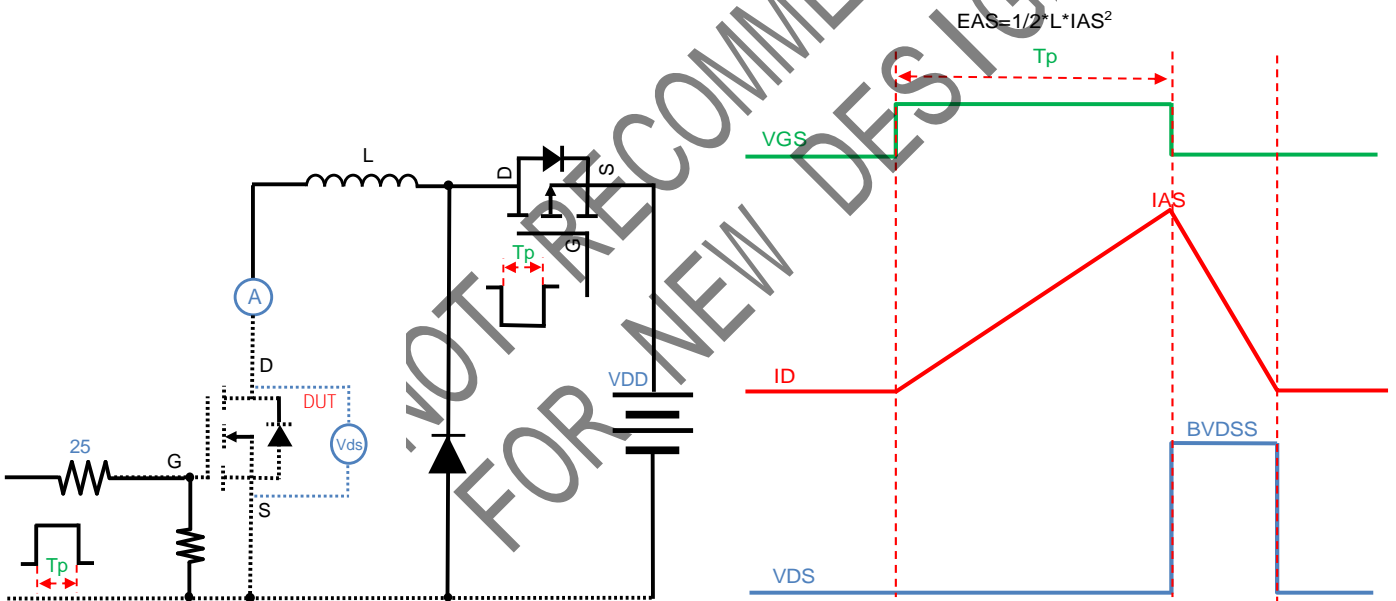


Figure A. Unclamped Inductive Switching (UIS) Test Circuit & Waveform

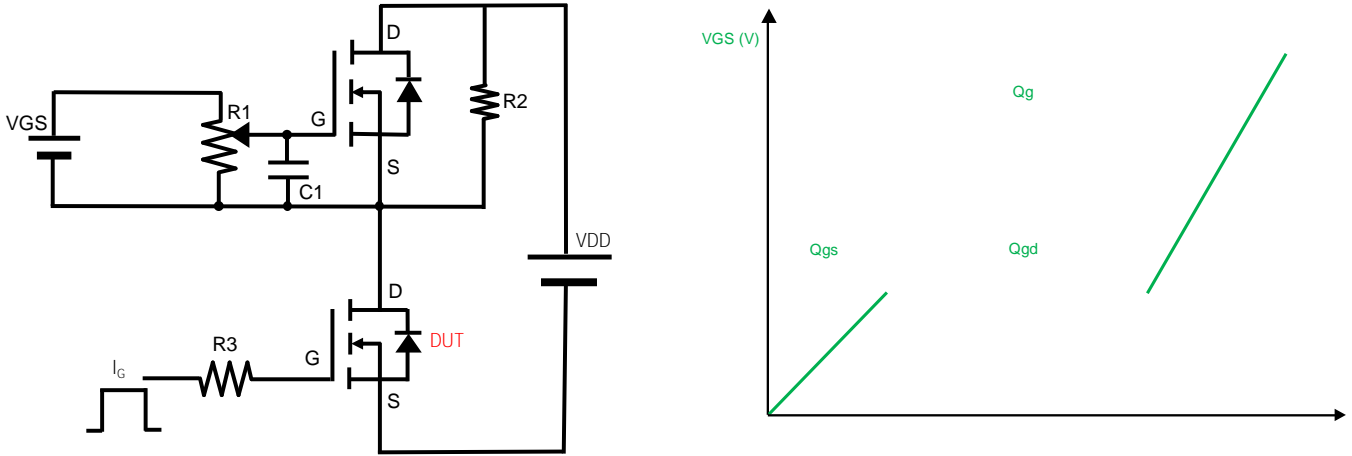


Figure B. Gate Charge Test Circuit & Waveform

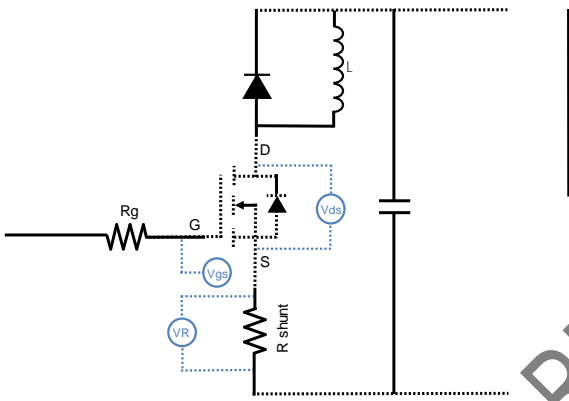


Figure C. Resistive Switching Test Circuit & Waveform

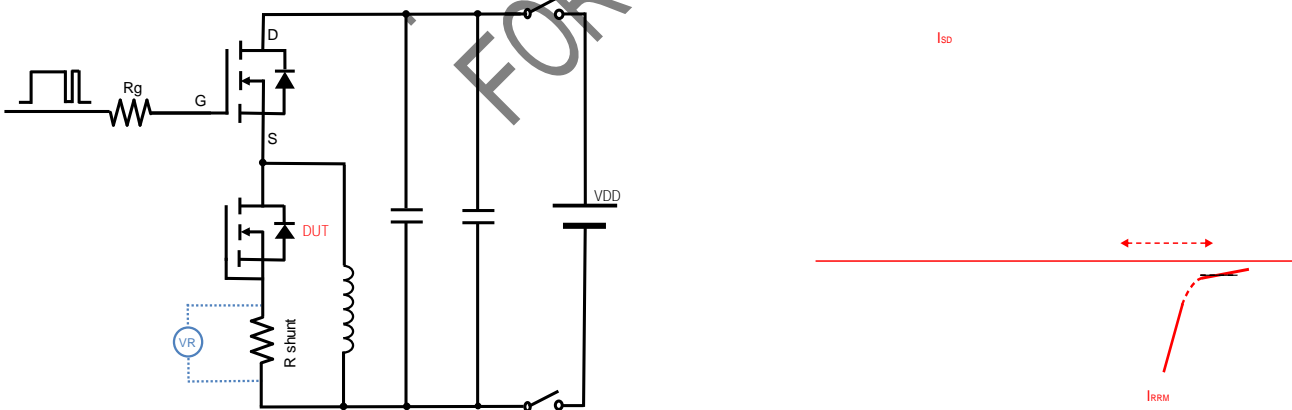
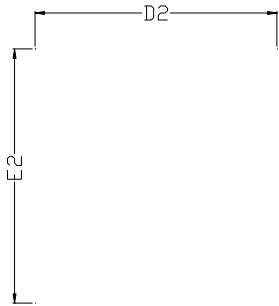


Figure D. Diode Recovery Test Circuit & Waveform



PDFN5060-8L-D-0.95MM Package information



Top View

Bottom View

Side View

| SYMBOL | MILLIMETER | | |
|--------|------------|-------|-------|
| | MIN | NOM | MAX |
| D | 5.15 | 5.35 | 5.55 |
| E | 5.95 | 6.05 | 6.15 |
| A | 0.85 | 0.95 | 1.00 |
| A1 | 0.203 BSC | | |
| A2 | 0.08 | | |
| D1 | 4.25 | 4.35 | 4.45 |
| E1 | 3.525 | 3.625 | 3.725 |
| D2 | 5.20 | | |
| E2 | 5.55 | | |
| L1 | 0.4 | | |

Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.10\text{mm}$.
3. The pad layout is for reference purposes only.

NOT RECOMMEND FOR NEW DESIGN



Disclaimer

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